L Number	Hits	Search Text	DB	Time stamp
1	1	5990512.pn. and polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:26
2	2	5898613.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:38
3	2	5825063.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:39
4	2	5875126.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:40
5	2	5990512.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:41
6	2	5627392.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:53
7	2	5825063.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:42
8	2	5990512.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:43
9	2	5875126.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:44
10	15	synaptic adj device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:46
11	80	synaptic and 257/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:49
12	108	synapse and 257/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:50
13	2	4783783.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:54
14	2	4935702.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:54

15	2	5933039.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:19
16	2	5939945.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:55
17	2	6134182.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:03
18	2	6320788.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:56
19	1	(first adj well) and (second adj well) and (tunnel or tunneling) and synaptic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:02
20	2	6452835.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:03
21	2	5990512.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:19
22	0	5990512.pn. and cmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:57
23	2	5844300.pn. and floating	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:15
24	42	well adj contact adj terminal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:16
26	196	(well adj contact) and (first adj well) and (second adj well)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:40
27	912	257/321.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:51
29	197	(plurality adj wells) with contact	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:47
30	885	257/314.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:51

31	1723	257/315.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 17:52
-	28	synapse adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 10:45
-	2	6144581.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:37
-	2	5898613.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 10:52
-	441	(first adj well) and (second adj well) and (tunnel or tunneling)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 10:54
-	2	(first adj well) and (second adj well) and (tunnel or tunneling) and synapse	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 16:02
-	2	6452835.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/20 15:26